

/ Descriptions

TO-92LM PNP Silicon PNP transistor in a TO-92LM Plastic Package.

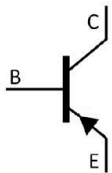
/ Features

, 2SC1384 2 3
Low $V_{CE(sat)}$, 2 3W output in complementary pair with 2SC1384.

/ Applications

AF power amplifier and driver applications.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	Q	R	S
h_{FE} Range	85~170	120~240	170~340

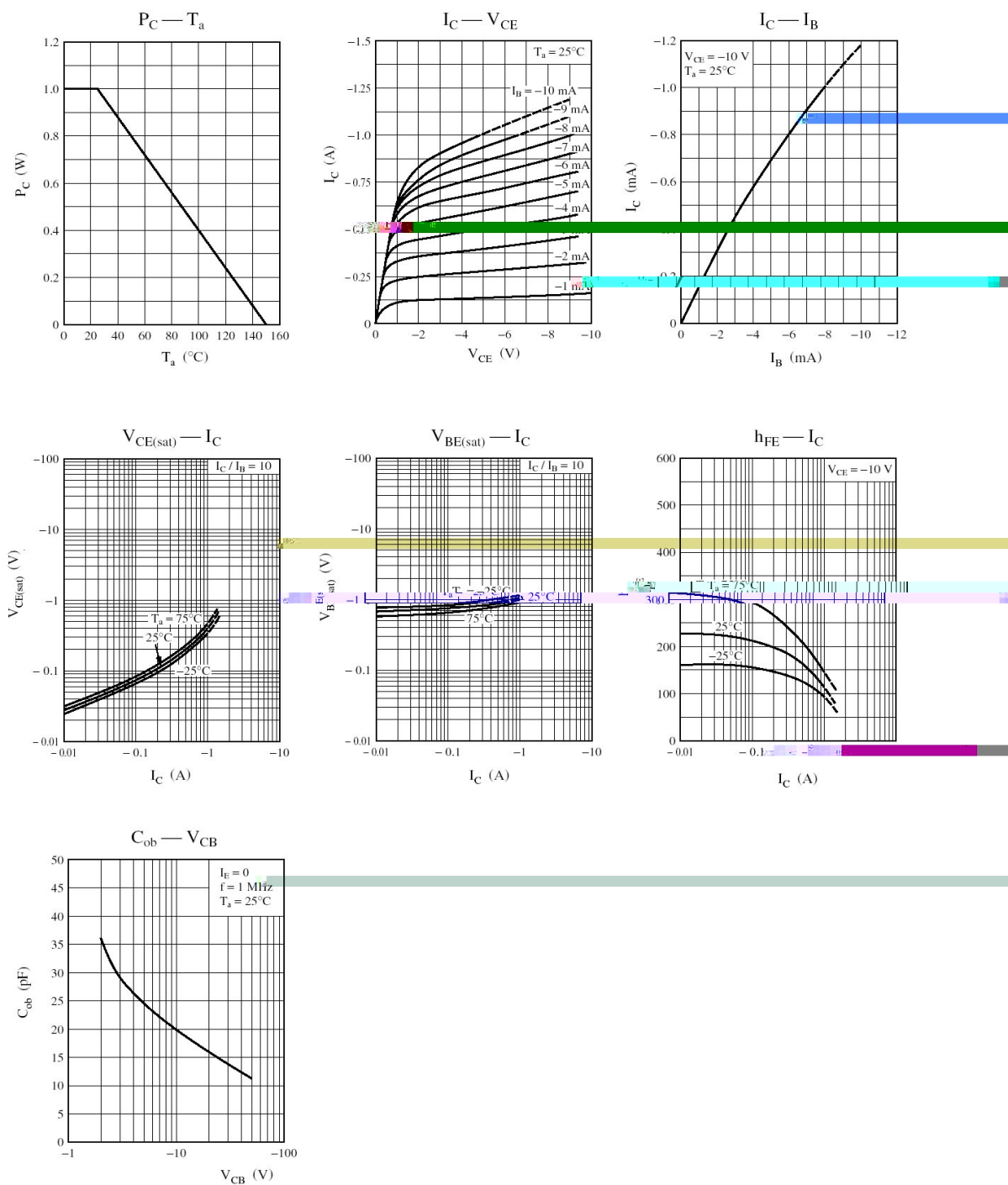
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-60	V
Collector to Emitter Voltage	V_{CEO}	-50	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-1.0	A
Collector Current – Continuous(Pulse)	I_{CP}	-1.5	A
Collector Power Dissipation	P_C	1.0	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 150	°C

/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector to Base Breakdown Voltage	V_{CBO}	$I_C = -10\mu A$ $I_E = 0$	-60			V
Collector to Emitter Breakdown Voltage	V_{CEO}	$I_C = -2.0mA$ $I_B = 0$	-50			V
Emitter to Base Breakdown Voltage	V_{EBO}	$I_E = -10\mu A$ $I_C = 0$	-5.0			V
Collector Cut-Off Current	I_{CBO}	$V_{CB} = -20V$ $I_E = 0$			-0.1	μA
DC Current Gain	$h_{FE(1)}$	$V_{CE} = -10V$ $I_C = -500mA$	85	160	340	
	$h_{FE(2)}$	$V_{CE} = -5.0V$ $I_C = -1.0A$	50	100		
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -500mA$ $I_B = -50mA$		-0.2	-0.4	V
Base to Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -500mA$ $I_B = -50mA$		-0.85	-1.2	V
Transition Frequency	f_T	$V_{CE} = -10V$ $I_C = -50mA$		200		MHz
Collector output capacitance	C_{ob}	$V_{CB} = -10V$ $I_E = 0$ $f = 1.0MHz$		20	30	pF

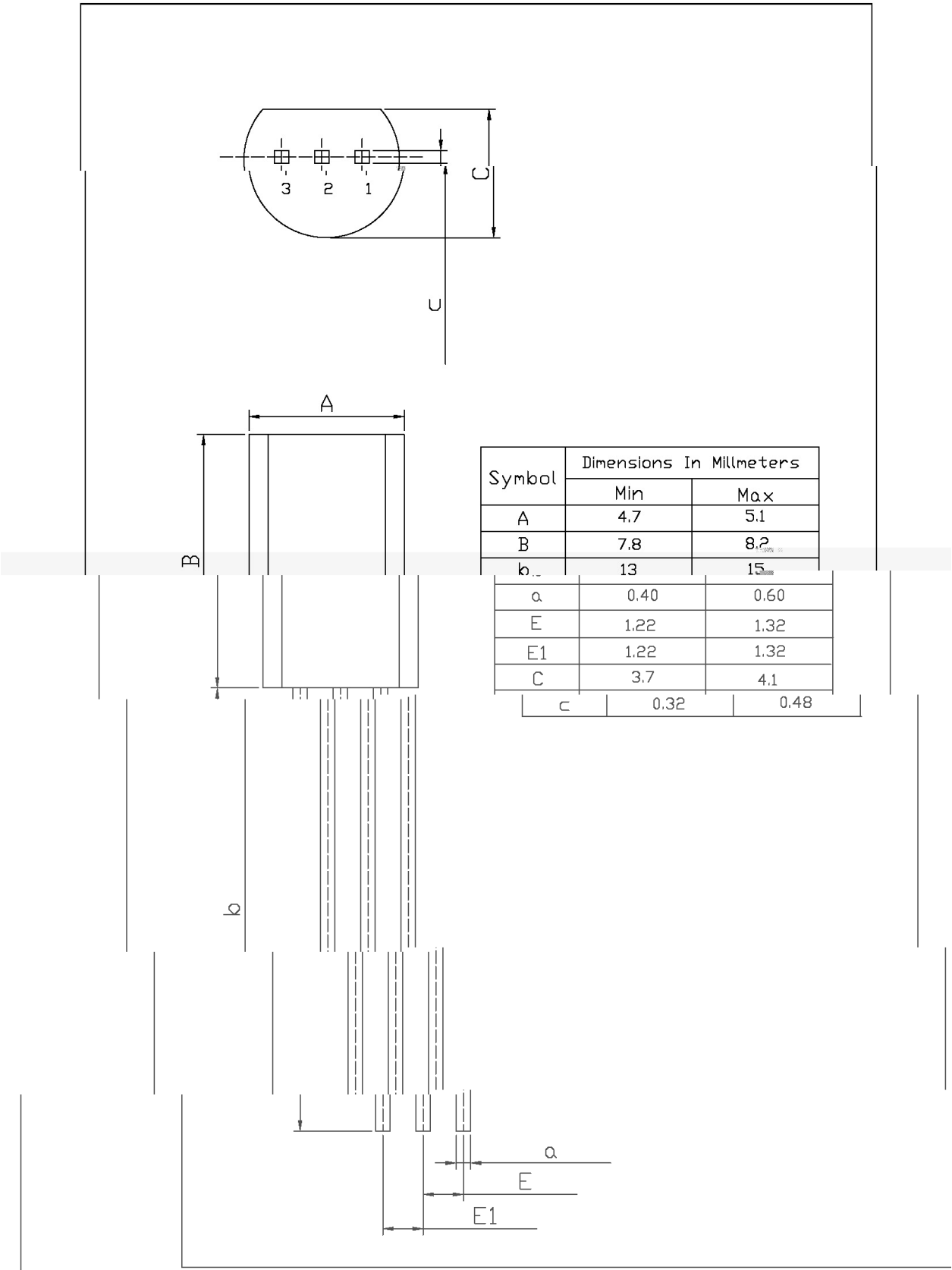
/ Electrical Characteristic Curve



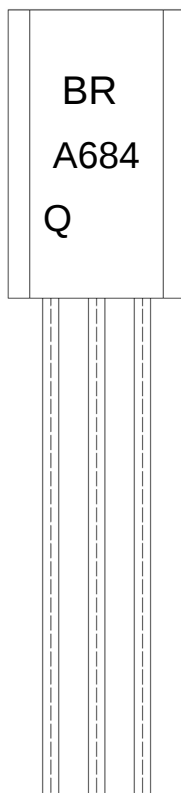
/ Package Dimensions

TO-92LM

Unit: mm



/ Marking Instructions



BR:

A684

Q: h_{FE}

Note:

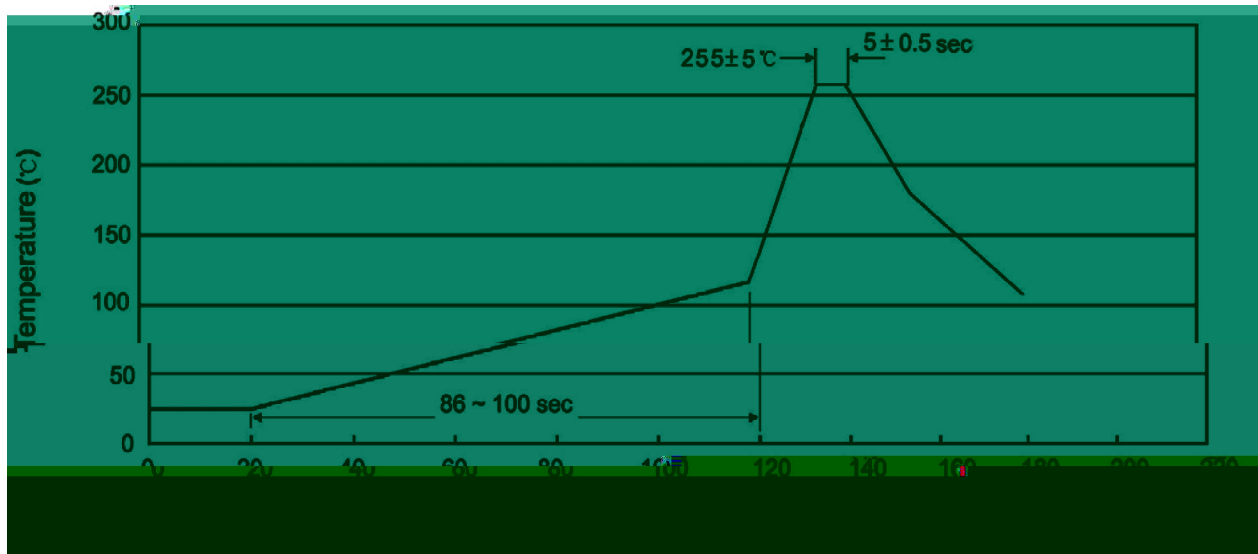
BR: Company Code.

A684: Product Type.

Q: h_{FE} Classifications Symbol

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|-----------|---|--------------------------------------|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255±5 | | 5±0.5sec; | 2.Peak Temp.:255±5 , Duration:5±0.5sec. | |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)		
	只 袋	袋 盒	只 盒	盒 箱	只 箱	袋	盒	箱

/ AMMO

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm3)	
	只 纸带	纸带 盒	纸带层 盒	盒 箱	只 箱	盒	箱
							小箱 大箱

/ Notices